

# Energy Structure of Two-Dimensional Graphene-Semiconductor Quantum Dot

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## ABSTRACT

Graphene is a newly discovered material that possesses unique electronic properties. It is a two-dimensional single-layered sheet in which the electrons are free and quasi-relativistic. These properties may open a door for many new electronic applications. In this paper we proposed a flat 2-dimensional circular graphene-semiconductor quantum dot. We have carried out theoretical studies including deriving the Dirac equation for the electrons inside the graphene-semiconductor quantum dot and solving the equation. We have established the energy structure as a function of the rotational quantum number and the size (radius) of the dot. The energy gap between the energy levels can be tuned with the radius of the quantum dot. It could be useful for quantum computation and single electron device application.

**Keywords:** Graphene; Quantum Dot; Dirac Equation; Semiconductor; Energy Levels

## 1. Introduction

Traditionally, quantum dots are nano-particles of a semiconductor material, such as chalcogenides of metals like cadmium or zinc, for example CdSe or ZnS. The size of the particles ranges from 2 to 10 nanometers in diameter [1]. Excitons, such as electrons or holes in a quantum dot are confined in all three spatial dimensions. Therefore, the electronic properties in quantum dot lay intermediate amid those of bulk materials and those of discrete atoms or molecules [1-4]. They were discovered at the beginning of the 1980s by Alexei Ekimov [1,5]. Graphene, a new class of two-dimensional (2D) carbon material with single-atom-thick layer features different from ball-like C60 and one-dimensional carbon nanotubes, has attracted attention in recent years [6-10]. Single atom layer graphene possesses unique electric properties. The energy bands of graphene can be described by a two-dimensional Dirac equation centered on hexagonal corners (Dirac points) of the honeycomb lattice Brillouin zone [11-13]. Particularly, the low energy band structure of graphene is gapless and the corresponding electronic states are found near two cones located at unequivalent corners of the Brillouin zone [12-14]. The low-energy carrier dynamics  $mv_F^2$  is equivalent to that of a 2D gas of massless charged fermions [12,15,16]. Many studies of electronic properties, transport properties of a nano-

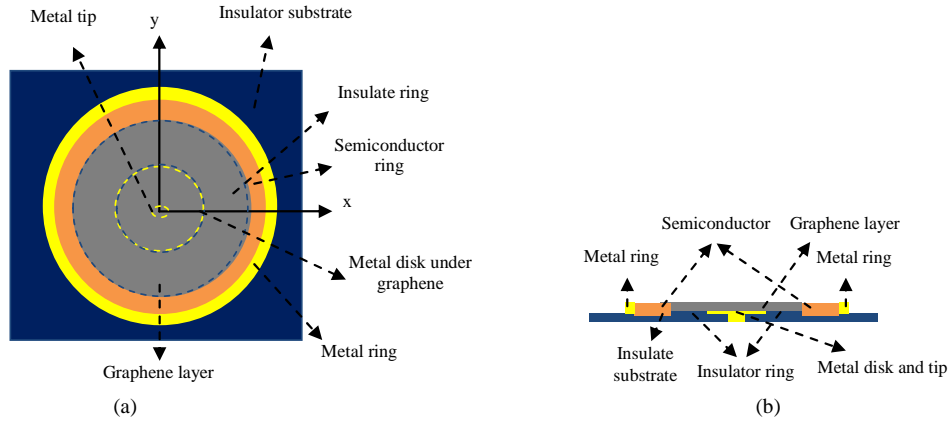
scale graphene strips were performed over the past years [14,17-24]. Transistors using graphene strip and graphene quantum dot have been fabricated recently [25,26]. Quantum dot may have applications in quantum computer and single-electron device.

The layered graphene quantum dot mentioned above which has two different boundary conditions corresponding to two types of graphene edges, *i.e.*, the zigzag and “armchair” [20,27], currently attracts intensively investigations world-wide [12,19].

In this paper we proposed a novel type of quantum dot, single layered two-dimensional (flat) graphene quantum dot composed of a small (in nanometer) circular graphene layer surrounded by a large gap semiconductor layer on an insulating substrate and carried out a theoretical study of such quantum dot. The Dirac equation in polar coordinate was derived and solved by variable-separation and series method. The energy structure of such quantum dot is found to have two discrete states and depends on the rotational quantum number and the size (radius) of the dot.

## 2. Electron Wave Functions in Graphene-Semiconductor Quantum Dot

The structure of the graphene-semiconductor quantum dot is shown in **Figure 1**. Electrons in graphene can be



**Figure 1. Structure of the graphene quantum dot. (a) Top view; (b) side view.**

treated as massless particles. Their behavior is governed by Dirac Hamiltonian [12,15,16].

The Hamiltonian including the energy gaps of the semiconductor film surrounding the graphene circular dot and a diagonal effective mass-like term  $mv_F^2$  is [12]

$$\hat{H} = v_F (\boldsymbol{\sigma} \cdot \mathbf{P}) + mv_F^2 \sigma_z + U,$$

and the Dirac equation is

$$\hat{H}\Psi = E\Psi \quad (1)$$

and

$$\Psi(\phi, \rho) = \begin{pmatrix} \psi_A(\phi, \rho) \\ \psi_B(\phi, \rho) \end{pmatrix} \quad (2)[12]$$

where  $\psi$  is the wave function as a function of  $\phi, \rho$  which are polar coordinates, angle and radius respectively.

Since the effective mass of electrons in graphene sheet near the corners of the Brillouin zone is close to massless, the Hamiltonian of the electrons is nearly relativistic. Hence, the energy of the electrons in the graphene sheet mostly arises from the spin-orbit interaction [12,28]. In polar coordinates, the momentum operator can be written as

$$\mathbf{P} = -i\hbar\nabla = -i\hbar \frac{\partial}{\partial \rho} \mathbf{e}_\rho - \frac{i\hbar}{\rho} \frac{\partial}{\partial \phi} \mathbf{e}_\phi \quad (3)$$

The Pauli vector is

$$\begin{aligned} \bar{\boldsymbol{\sigma}} &= \bar{\sigma}_1 \mathbf{i} + \bar{\sigma}_2 \mathbf{j} \\ &= \bar{\sigma}_1 (\cos \phi \mathbf{e}_\rho - \sin \phi \mathbf{e}_\phi) + \bar{\sigma}_2 (\sin \phi \mathbf{e}_\rho + \cos \phi \mathbf{e}_\phi) \\ &= \begin{pmatrix} 0 & \cos \phi - i \sin \phi \\ \cos \phi + i \sin \phi & 0 \end{pmatrix} \mathbf{e}_\rho \\ &\quad + \begin{pmatrix} 0 & -\sin \phi - i \cos \phi \\ -\sin \phi + i \cos \phi & 0 \end{pmatrix} \mathbf{e}_\phi \end{aligned} \quad (4)$$

Combining Equations (3) and (4), we obtain

$$\begin{aligned} \bar{\boldsymbol{\sigma}} \cdot \mathbf{P} &= -i\hbar \begin{pmatrix} 0 & \cos \phi - i \sin \phi \\ \cos \phi + i \sin \phi & 0 \end{pmatrix} \frac{\partial}{\partial \rho} \\ &\quad + i\hbar \begin{pmatrix} 0 & \sin \phi + i \cos \phi \\ \sin \phi - i \cos \phi & 0 \end{pmatrix} \frac{1}{\rho} \frac{\partial}{\partial \phi} \end{aligned}$$

The Hamiltonian

$$\begin{aligned} \hat{H} &= -i\hbar v_F \begin{pmatrix} 0 & \cos \phi - i \sin \phi \\ \cos \phi + i \sin \phi & 0 \end{pmatrix} \frac{\partial}{\partial \rho} \\ &\quad + i\hbar v_F \begin{pmatrix} 0 & \sin \phi + i \cos \phi \\ \sin \phi - i \cos \phi & 0 \end{pmatrix} \frac{1}{\rho} \frac{\partial}{\partial \phi} \\ &\quad + mv_F^2 \begin{pmatrix} 1 & 0 \\ 0 & -1 \end{pmatrix} + U(\rho, \phi) \end{aligned}$$

The Dirac Equation (1) then becomes

$$\begin{aligned} &\begin{pmatrix} -i\hbar v_F (\cos \phi - i \sin \phi) \frac{\partial \psi_B}{\partial \rho} + i\hbar v_F (\sin \phi + i \cos \phi) \frac{1}{\rho} \frac{\partial \psi_B}{\partial \phi} \\ -i\hbar v_F (\cos \phi + i \sin \phi) \frac{\partial \psi_A}{\partial \rho} + i\hbar v_F (\sin \phi - i \cos \phi) \frac{1}{\rho} \frac{\partial \psi_A}{\partial \phi} \end{pmatrix} \\ &= \begin{pmatrix} (E - U - mv_F^2) \psi_A \\ (E - U + mv_F^2) \psi_B \end{pmatrix} \end{aligned} \quad (5)$$

Equation (5) consists of two equations. These are:

$$\begin{aligned} &-i\hbar v_F (\sin \phi + i \cos \phi) \frac{\partial \psi_B}{\partial \rho} + \hbar v_F (-\cos \phi + i \sin \phi) \frac{1}{\rho} \frac{\partial \psi_B}{\partial \phi} \\ &= (E - U - mv_F^2) \psi_A \end{aligned} \quad (6)$$

and

$$\begin{aligned} &\hbar v_F (\sin \phi - i \cos \phi) \frac{\partial \psi_A}{\partial \rho} + \hbar v_F (\cos \phi + i \sin \phi) \frac{1}{\rho} \frac{\partial \psi_A}{\partial \phi} \\ &= (E - U + mv_F^2) \psi_B \end{aligned} \quad (7)$$

Letting

$$\psi_A(\phi, \rho) = \varphi_A(\rho) e^{i\phi}$$

and

$$\psi_B(\phi, \rho) = \varphi_B(\rho) e^{i\phi}$$

where

$$l = 0, 1, 2, 3, \dots$$

Substituting these two functions into Equations (6) and (7), we obtain the following two equations:

$$-\hbar v_F (\sin \phi + i \cos \phi) \frac{d\varphi_B}{d\rho} + l \hbar v_F (-\sin \phi - i \cos \phi) \frac{1}{\rho} \varphi_B = (E - U - mv_F^2) \varphi_A \tag{8}$$

$$\hbar v_F (\sin \phi - i \cos \phi) \frac{d\varphi_A}{d\rho} + l \hbar v_F (-\sin \phi + i \cos \phi) \frac{1}{\rho} \varphi_A = (E - U + mv_F^2) \varphi_B \tag{9}$$

Differentiating Equation (8), one finds

$$\begin{aligned} &\hbar v_F (-\sin \phi - i \cos \phi) \frac{d^2 \varphi_B}{d\rho^2} \\ &+ l \hbar v_F (-\sin \phi - i \cos \phi) \left( -\frac{1}{\rho^2} \varphi_B + \frac{1}{\rho} \frac{d\varphi_B}{d\rho} \right) \\ &= (E - U - mv_F^2) \frac{d\varphi_A}{d\rho} - U' \varphi_A \end{aligned} \tag{10}$$

From Equation (9), one can find

$$\frac{d\varphi_A}{d\rho} = \frac{l}{\rho} \varphi_A + \frac{E - U + mv_F^2}{\hbar v_F (\sin \phi - i \cos \phi)} \varphi_B \tag{11}$$

Substituting Equation (11) into Equation (10), we find

$$\begin{aligned} \frac{d^2 \varphi_B}{d\rho^2} + \frac{l}{\rho} \frac{d\varphi_B}{d\rho} - \frac{l}{\rho^2} \varphi_B &= \frac{E - U - mv_F^2}{-\hbar v_F (\sin \phi + i \cos \phi)} \\ &\cdot \left[ \frac{l}{\rho} \varphi_A + \frac{E - U + mv_F^2}{\hbar v_F (\sin \phi - i \cos \phi)} \varphi_B \right. \\ &\quad \left. - \frac{U'}{-\hbar v_F (\sin \phi + i \cos \phi)} \varphi_A \right] \end{aligned} \tag{12}$$

From Equation (8), we also find

$$\begin{aligned} \varphi_A &= \frac{-\hbar v_F (\sin \phi + i \cos \phi) \frac{d\varphi_B}{d\rho}}{E - U - mv_F^2} \\ &+ \frac{l \hbar v_F (-\sin \phi - i \cos \phi) \varphi_B}{E - U - mv_F^2 \rho} \end{aligned} \tag{13}$$

Substituting Equation (13) into Equation (12), Equation (12) becomes

$$\begin{aligned} \frac{d^2 \varphi_B}{d\rho^2} + \frac{l}{\rho} \frac{d\varphi_B}{d\rho} - \frac{l}{\rho^2} \varphi_B &= \frac{(E - U - mv_F^2) l}{-\hbar v_F (\sin \phi + i \cos \phi) \rho} \\ &\cdot \left[ \frac{-\hbar v_F (\sin \phi + i \cos \phi) \frac{d\varphi_B}{d\rho}}{E - U - mv_F^2} + \frac{l \hbar v_F (-\sin \phi - i \cos \phi)}{(E - U - mv_F^2) \rho} \varphi_B \right] \\ &+ \frac{E - U - mv_F^2}{-\hbar v_F (\sin \phi + i \cos \phi)} \cdot \frac{E - U + mv_F^2}{\hbar v_F (\sin \phi - i \cos \phi)} \varphi_B \\ &- \frac{U'}{-\hbar v_F (\sin \phi + i \cos \phi)} \cdot \left[ \frac{-\hbar v_F (\sin \phi + i \cos \phi) \frac{d\varphi_B}{d\rho}}{E - U - mv_F^2} \right. \\ &\quad \left. + \frac{l \hbar v_F (-\sin \phi - i \cos \phi)}{(E - U - mv_F^2) \rho} \varphi_B \right] \end{aligned} \tag{14}$$

After some cancelations, Equation (14) becomes

$$\begin{aligned} \frac{d^2 \varphi_B}{d\rho^2} - \frac{U'}{E - U - mv_F^2} \frac{d\varphi_B}{d\rho} \\ - \left( \frac{l(l+1)}{\rho^2} - \frac{(E - U)^2 - m^2 v_F^4}{\hbar^2 v_F^2} + \frac{U'}{E - U - mv_F^2} \right) \varphi_B = 0 \end{aligned} \tag{14'}$$

For inside the graphene quantum dot,  $\rho < \rho_0$ , the potential energy  $U = 0$ . And  $U' = 0$ . Therefore, Equation (14) becomes

$$\frac{d^2 \varphi_B}{d\rho^2} - \left( \frac{l(l+1)}{\rho^2} - \frac{(E)^2 - m^2 v_F^4}{\hbar^2 v_F^2} \right) \varphi_B = 0 \tag{14''}$$

Letting  $\xi = \frac{\rho}{\rho_0}$ , and  $\xi < 1$ , Equation (14)'' then becomes

$$\begin{aligned} \frac{d^2 \varphi_B}{d\xi^2} - \frac{l(l+1)}{\xi^2} \varphi_B &= - \left[ \left( \frac{\rho_0 E}{\hbar v_F} \right)^2 - \left( \frac{\rho_0 m v_F}{\hbar} \right)^2 \right] \varphi_B \\ &= - [\varepsilon^2 - \Delta^2] \varphi_B, \end{aligned} \tag{15}$$

where

$$\varepsilon = \frac{\rho_0 E}{\hbar v_F}, \quad \text{and} \quad \Delta = \frac{\rho_0 m v_F}{\hbar}$$

For  $\xi > 1$ , i.e.  $\rho > \rho_0$ , outside the dot, electrons are no longer in graphene layer. Instead, electrons are in semiconductor which should be described by Schrodinger equation. We will study this case in other paper. In this paper, we only deal with the case that the energy gap of the semiconductor is infinite. The potential function can be expressed as

$$U(\xi, \theta) = \begin{cases} 0 & \xi < 1 \\ \infty & \xi \geq 1 \end{cases}$$

### 3. Wave Function and Energy States of the Electrons inside the Dot

To find the wave functions and the energy states of the electrons inside the quantum dot, we have to first solve Equation (15). Equation (15) is an eigen value-eigen function equation. From this equation, one can see that the eigen values  $\varepsilon^2 - \Delta^2$  can be positive or negative. Since the value for  $\Delta$  is usually very small. Hence let us first consider  $\varepsilon^2 - \Delta^2$  is positive.

Letting

$$k^2 = \varepsilon^2 - \Delta^2$$

assuming

$$\varphi_B = \phi_B(\xi) e^{ik\xi},$$

then

$$\frac{d\varphi_B}{d\xi} = \frac{d\phi_B}{d\xi} e^{ik\xi} + \phi_B(ik) e^{ik\xi},$$

and

$$\frac{d^2\varphi_B}{d\xi^2} = \frac{d^2\phi_B}{d\xi^2} e^{ik\xi} + 2(ik) \frac{d\phi_B}{d\xi} e^{ik\xi} - k^2 \phi_B e^{ik\xi}$$

Substituting the above function and their derivatives into Equation (15), we find the equation of  $\phi_B(\xi)$

$$\frac{d^2\phi_B}{d\xi^2} + 2ik \frac{d\phi_B}{d\xi} = \frac{l(l+1)}{\xi^2} \phi_B \quad (16)$$

assuming

$$\phi_B(\xi) = \xi^s L(\xi),$$

then

$$\frac{d\phi_B}{d\xi} = s\xi^{s-1} L + \xi^s \frac{dL}{d\xi}$$

and

$$\frac{d^2\phi_B}{d\xi^2} = s(s-1)\xi^{s-2} L + 2s\xi^{s-1} \frac{dL}{d\xi} + \xi^s \frac{d^2L}{d\xi^2}$$

Substituting the above two equations into Equation (16), we obtain the following equation

$$\xi^2 \frac{d^2L}{d\xi^2} + (2s\xi + 2ik\xi^2) \frac{dL}{d\xi} + [2iks\xi + s(s-1) - l(l+1)] L = 0 \quad (17)$$

Letting  $L(\xi) = \sum_{n=0}^{\infty} a_n \xi^n$ , and substituting this series into Equation (17), we obtain the following equation

$$\sum_{n=0}^{\infty} a_n n(n-1) \xi^n + 2s \sum_{n=0}^{\infty} n a_n \xi^n + 2ik \sum_{n=0}^{\infty} n a_n \xi^{n+1} + 2iks \sum_{n=0}^{\infty} a_n \xi^{n+1} + [s(s-1) - l(l+1)] \sum_{n=0}^{\infty} a_n \xi^n = 0 \quad (18)$$

From Equation (18), we determine the recursion relation of the series coefficients.

$$\xi^0 : [s(s-1) - l(l+1)] a_0 = 0$$

$$\xi^1 : [2s + s(s-1) - l(l+1)] a_1 + 2iks a_0 = 0 \quad (19)$$

$$\xi^2 : [2 + 2s \cdot 2 + s(s-1) - l(l+1)] a_2 + (2ik + 2iks) a_1 = 0$$

$$\xi^3 : [3 \cdot 2 + 2s \cdot 3 + s(s-1) - l(l+1)] a_3 + (2ik \cdot 2 + 2iks) a_2 = 0 \quad (20)$$

⋮

$$\xi^n : [n(n-1) + 2sn + s(s-1) - l(l+1)] a_n + [2ik(n-1) + 2iks] a_{n-1} = 0 \quad (21)$$

The recursion relation may be extrapolated as

$$a_n = \frac{-2ik(n+l)}{n(n+2l+1)} a_{(n-1)} = (-2ik)^n \frac{(n+l)!(2l+1)!}{n!(n+2l+1)! l!} a_0 = (i)^n \frac{(n+l)!(2l+1)!}{n!(n+2l+1)! l!} (2k)^n a_0 \quad (22)$$

For no trivial solution,  $a_0 \neq 0$ , then  $s = l+1$

Finally,

$$\begin{aligned} \varphi_B &= \xi^{l+1} e^{ik\xi} \frac{(2l)! a_0}{l!} \sum_{n=0}^{\infty} \frac{(n+l)!}{n!(n+l+1)!} (i)^n (2k\xi)^n \\ &= \xi^{l+1} e^{ik\xi} \frac{(2l)! a_0}{l!} \left[ \sum_{n=0}^{\infty} (-1)^n \frac{(2n+l)!}{2n!(2n+l+1)!} (2k\xi)^{2n} + i \sum_{n=0}^{\infty} (-1)^n \frac{(2n+l+1)!}{(2n+1)!(2n+l+2)!} (2k\xi)^{2n+1} \right] \end{aligned} \quad (23)$$

The general solution  $\varphi_B$  can be formed as

$$\begin{aligned} \varphi_B(\xi) &= \xi^{l+1} \frac{(2l)!}{l!} \left\{ A \left[ \cos(k\xi) \sum_{n=0}^{\infty} (-1)^n \frac{(2n+l)!}{2n!(2n+l+1)!} (2k\xi)^{2n} - \sin(k\xi) \sum_{n=0}^{\infty} (-1)^n \frac{(2n+l+1)!}{(2n+1)!(2n+l+2)!} (2k\xi)^{2n+1} \right] \right. \\ &\quad \left. + B \left[ \sin(k\xi) \sum_{n=0}^{\infty} (-1)^n \frac{(2n+l)!}{2n!(2n+l+1)!} (2k\xi)^{2n} + \cos(k\xi) \sum_{n=0}^{\infty} (-1)^n \frac{(2n+l+1)!}{(2n+1)!(2n+l+2)!} (2k\xi)^{2n+1} \right] \right\} \\ &\cong \xi^{l+1} \frac{(2l)!}{l!} \left\{ A \left[ \cos(k\xi) \left( \frac{1}{l+1} - \frac{4k^2}{2(l+3)} \xi^2 + \frac{2k^4}{3(l+5)} \xi^4 \right) - \sin(k\xi) \left( \frac{2k}{l+2} \xi - \frac{8k^3}{6(l+4)} \xi^3 + \frac{4k^5}{15(l+6)} \xi^5 \right) \right] \right. \\ &\quad \left. + B \left[ \sin(k\xi) \left( \frac{1}{l+1} - \frac{4k^2}{2(l+3)} \xi^2 + \frac{2k^4}{3(l+5)} \xi^4 \right) + \cos(k\xi) \left( \frac{2k}{l+2} \xi - \frac{8k^3}{6(l+4)} \xi^3 + \frac{4k^5}{15(l+6)} \xi^5 \right) \right] \right\} \end{aligned} \tag{24}$$

One can note that the series above converges fast. Therefore, we make the third order-approximation. The B-component of the wave function then can approximately be obtained as

$$\begin{aligned} \psi_B(\phi, \rho) &= e^{i\phi} \varphi_B(\xi) \cong e^{i\phi} \xi^{l+1} \frac{(2l)!}{l!} \left\{ A \left[ \cos(k\xi) \left( \frac{1}{l+1} - \frac{4k^2}{2(l+3)} \xi^2 + \frac{2k^4}{3(l+5)} \xi^4 \right) \right. \right. \\ &\quad \left. \left. - \sin(k\xi) \left( \frac{2k}{l+2} \xi - \frac{8k^3}{6(l+4)} \xi^3 + \frac{4k^5}{15(l+6)} \xi^5 \right) \right] \right. \\ &\quad \left. + B \left[ \sin(k\xi) \left( \frac{1}{l+1} - \frac{4k^2}{2(l+3)} \xi^2 + \frac{2k^4}{3(l+5)} \xi^4 \right) \right. \right. \\ &\quad \left. \left. + \cos(k\xi) \left( \frac{2k}{l+2} \xi - \frac{8k^3}{6(l+4)} \xi^3 + \frac{4k^5}{15(l+6)} \xi^5 \right) \right] \right\} \end{aligned} \tag{25}$$

With Equation (13), one can find the A-component of the wave function.

When  $\rho = \rho_0$ , the boundary conditions are:

$$\psi_A(\phi, \rho_0) = 0$$

or

$$\begin{aligned} &A \left\{ [(2l+1)\cos k - k \sin k] \cdot \left( \frac{1}{l+1} - \frac{2k^2}{l+3} + \frac{2k^4}{3(l+5)} \right) - [(2l+1)\sin k + k \cos k] \cdot \left( \frac{2k}{l+2} - \frac{4k^3}{3(l+4)} + \frac{4k^5}{15(l+6)} \right) \right. \\ &\quad \left. - \left( \frac{4k^2}{l+3} - \frac{8k^4}{(l+5)} \right) \cos k - \left( \frac{2k}{l+2} - \frac{4k^3}{l+4} + \frac{4k^5}{3(l+6)} \right) \sin k \right\} + B \left\{ [(2l+1)\sin k + k \cos k] \cdot \left( \frac{1}{l+1} - \frac{2k^2}{l+3} + \frac{2k^4}{3(l+5)} \right) \right. \\ &\quad \left. + [(2l+1)\cos k - k \sin k] \cdot \left( \frac{2k}{l+2} - \frac{4k^3}{3(l+4)} + \frac{4k^5}{15(l+6)} \right) - \left( \frac{4k^2}{l+3} - \frac{8k^4}{(l+5)} \right) \sin k + \left( \frac{2k}{l+2} - \frac{4k^3}{l+4} + \frac{4k^5}{3(l+6)} \right) \cos k \right\} = 0 \end{aligned} \tag{26}$$

and

$$\psi_B(\phi, \rho_0) = 0, \text{ i.e.}$$

$$\begin{aligned} &A \left[ \cos k \left( \frac{1}{l+1} - \frac{2k^2}{l+3} + \frac{2k^4}{3(l+5)} \right) - \sin k \left( \frac{2k}{l+2} - \frac{4k^3}{3(l+4)} + \frac{4k^5}{15(l+6)} \right) \right] \\ &\quad + B \left[ \sin k \left( \frac{1}{l+1} - \frac{2k^2}{l+3} + \frac{2k^4}{3(l+5)} \right) + \cos k \left( \frac{2k}{l+2} - \frac{4k^3}{3(l+4)} + \frac{4k^5}{15(l+6)} \right) \right] = 0 \end{aligned} \tag{27}$$

From Equations (26) and (27), one can conclude that only the value of the determinant of coefficients A and B in Equations (26) and (27) equals to zero, i.e..

$$\begin{aligned}
 & \left\{ [(2l+1)\cos k - k \sin k] \cdot \left( \frac{1}{l+1} - \frac{2k^2}{l+3} + \frac{2k^4}{3(l+5)} \right) - [(2l+1)\sin k + k \cos k] \cdot \left( \frac{2k}{l+2} - \frac{4k^3}{3(l+4)} + \frac{4k^5}{15(l+6)} \right) \right. \\
 & \left. - \left( \frac{4k^2}{l+3} - \frac{8k^4}{(l+5)} \right) \cos k - \left( \frac{2k}{l+2} - \frac{4k^3}{l+4} + \frac{4k^5}{15(l+6)} \right) \sin k \right\} \\
 & \cdot \left[ \sin k \left( \frac{1}{l+1} - \frac{2k^2}{l+3} + \frac{2k^4}{3(l+5)} \right) + \cos k \left( \frac{2k}{l+2} - \frac{4k^3}{3(l+4)} + \frac{4k^5}{15(l+6)} \right) \right] \\
 & - \left\{ [(2l+1)\sin k + k \cos k] \cdot \left( \frac{1}{l+1} - \frac{2k^2}{l+3} + \frac{2k^4}{3(l+5)} \right) + [(2l+1)\cos k - k \sin k] \cdot \left( \frac{2k}{l+2} - \frac{4k^3}{3(l+4)} + \frac{4k^5}{15(l+6)} \right) \right. \\
 & \left. - \left( \frac{4k^2}{l+3} - \frac{8k^4}{l+5} \right) \sin k + \left( \frac{2k}{l+2} - \frac{4k^3}{l+4} + \frac{4k^5}{15(l+6)} \right) \cos k \right\} \\
 & \cdot \left[ \cos k \left( \frac{1}{l+1} - \frac{2k^2}{l+3} + \frac{2k^4}{3(l+5)} \right) - \sin k \left( \frac{2k}{l+2} - \frac{4k^3}{3(l+4)} + \frac{4k^5}{15(l+6)} \right) \right] = 0,
 \end{aligned} \tag{28}$$

then the wave functions  $\psi_A, \psi_B$  have nonzero solutions. And the above equation determines the values of  $k$  and then the energy level  $E$ . The above equation was numerically solved. And we found the solutions of  $k$  as a function of  $l$  which are plotted in **Figure 2**. Then the energy level

$$E = \frac{\hbar V_F}{\rho_0} \sqrt{k^2 + \Delta^2} \tag{29}$$

Typically

$$\hbar V_F = 0.539 \text{ eV} \cdot \text{nm} \quad [12]$$

and

$$\Delta = 9.28 \times 10^{-3} (\text{nm})^{-1} \cdot \rho_0 (\text{nm}) \quad [12],$$

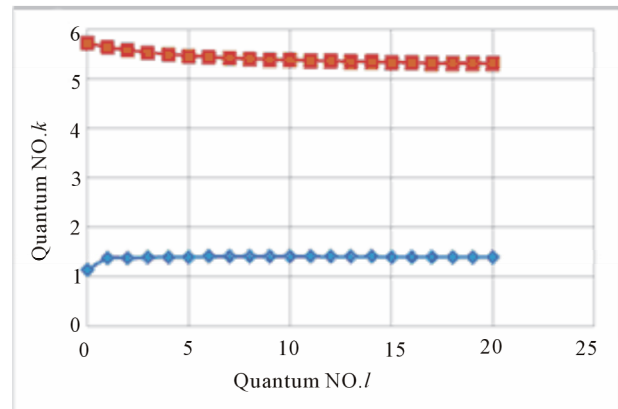
then

$$E = \frac{0.539}{\rho_0} \sqrt{k^2 + 8.6 \times 10^{-5} \rho_0^2} \text{ (eV)}$$

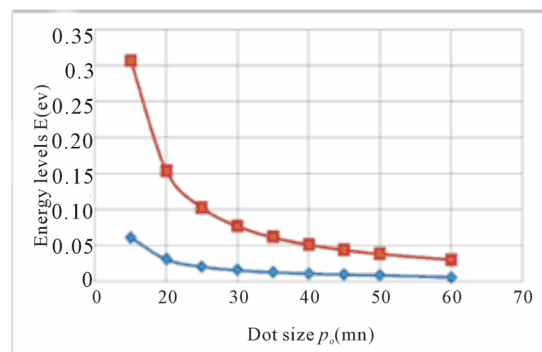
This relation for  $l = 0$  is plotted in **Figure 3**.

#### 4. Conclusion

We have derived and solved the Dirac equation for a flat circular graphene-semiconductor quantum dot. The series method was employed and the recursion relation of the coefficients of the series was found. The wave function  $\psi_A, \psi_B$  was approximately established. The energy related quantum number  $k$  were obtained as a function of rotation quantum number  $l$ . one can see that for each  $l$  there are two values of  $k$ . Namely, there are two energy levels. The smaller value of  $k$ , *i.e.* the first energy level increases slightly with  $l$  when  $l < 1$ . After  $l > 1$ ,  $k$  is approximately a constant. The higher  $k$ , *i.e.* the higher energy level decreases slightly with increasing  $l$  and as-



**Figure 2. Quantum number  $k$  versus quantum number  $l$ .**



**Figure 3. Energy levels versus the size of the dot for  $l = 0$ .**

ymptotically approaches a constant. These two states of the electrons in such graphene quantum dot are clear and stable. From **Figure 3** we can see that the energy levels  $E$  of the quantum dot decrease with the increasing size of the quantum dot  $\rho_0$ . Therefore, the energy gap between these two energy levels may be tuned with the radius of the quantum dot. It may have potential applications in

quantum computation and developing a single-electron device.

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